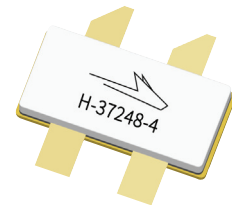


# PXAC261002FC

## Thermally-Enhanced High Power RF LDMOS FET 100 W, 28 V, 2490 – 2690 MHz

### Description

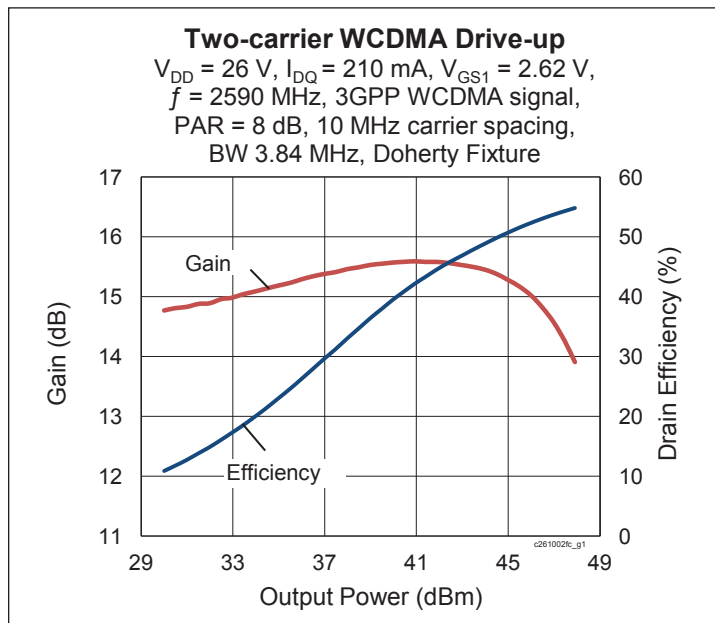
The PXAC261002FC is a 100-watt LDMOS FET with an asymmetric design intended for use in multi-standard cellular power amplifier applications in the 2496 to 2690 MHz frequency band. Features include dual-path design, high gain and a thermally-enhanced package with earless flanges. Manufactured with Wolfspeed's advanced LDMOS process, this device provides excellent thermal performance and superior reliability.



PXAC261002FC  
Package H-37248-4

### Features

- Broadband internal input and output matching
- Asymmetric design
  - Main: P1dB = 40 W Typ
  - Peak: P1dB = 70 W Typ
- Typical Pulsed CW performance, 2590 MHz, 26 V, 160  $\mu$ s, 10% duty cycle, Doherty Configuration
  - Output power at P1dB = 46.5 dBm
  - Output power at P3dB = 50.1 dBm
- Capable of handling 10:1 VSWR @28 V, 100 W (CW) output power
- Integrated ESD protection : Human Body Model, Class 1C (per JESD22-A114)
- Low thermal resistance
- Pb-free and RoHS compliant



### RF Characteristics

#### Two-carrier WCDMA Specifications (tested in Wolfspeed production Doherty test fixture)

$V_{DD} = 26$  V,  $I_{DQ} = 210$  mA,  $P_{OUT} = 18$  W avg,  $V_{GS2} = 1.4$  V,  $f_1 = 2550$  MHz,  $f_2 = 2590$  MHz, 3GPP signal, 3.84 MHz channel bandwidth, 8 dB peak/average @ 0.01% CCDF

| Characteristic                                                                      | Symbol   | Min  | Typ  | Max | Unit |
|-------------------------------------------------------------------------------------|----------|------|------|-----|------|
| Gain                                                                                | $G_{ps}$ | 14.1 | 15.1 | —   | dB   |
| Drain Efficiency                                                                    | $\eta_D$ | 46   | 49   | —   | %    |
| Intermodulation Distortion                                                          | IMD      | —    | -22  | -21 | dBc  |
| Output PAR at 0.01% probability on CCDF<br>(one-carrier WCDMA, 2585 MHz, 10 dB PAR) | OPAR     | 7.5  | —    | —   | dB   |

All published data at  $T_{CASE} = 25^\circ\text{C}$  unless otherwise indicated

ESD: Electrostatic discharge sensitive device—observe handling precautions!

**DC Characteristics** (each side)

| Characteristic                 | Conditions                                               | Symbol        | Min | Typ  | Max | Unit          |
|--------------------------------|----------------------------------------------------------|---------------|-----|------|-----|---------------|
| Drain-Source Breakdown Voltage | $V_{GS} = 0\text{ V}$ , $I_{DS} = 10\text{ mA}$          | $V_{(BR)DSS}$ | 65  | —    | —   | V             |
| Drain Leakage Current          | $V_{DS} = 28\text{ V}$ , $V_{GS} = 0\text{ V}$           | $I_{DSS}$     | —   | —    | 1   | $\mu\text{A}$ |
|                                | $V_{DS} = 63\text{ V}$ , $V_{GS} = 0\text{ V}$           | $I_{DSS}$     | —   | —    | 10  | $\mu\text{A}$ |
| Gate Leakage Current           | $V_{GS} = 10\text{ V}$ , $V_{DS} = 0\text{ V}$           | $I_{GSS}$     | —   | —    | 1   | $\mu\text{A}$ |
| On-State Resistance            | (main) $V_{GS} = 10\text{ V}$ , $V_{DS} = 0.1\text{ V}$  | $R_{DS(on)}$  | —   | 0.3  | —   | $\Omega$      |
|                                | (peak) $V_{GS} = 10\text{ V}$ , $V_{DS} = 0.1\text{ V}$  | $R_{DS(on)}$  | —   | 0.16 | —   | $\Omega$      |
| Operating Gate Voltage         | (main) $V_{DS} = 26\text{ V}$ , $I_{DQ} = 210\text{ mA}$ | $V_{GS}$      | 2.1 | 2.6  | 3.1 | V             |
|                                | (peak) $V_{DS} = 26\text{ V}$ , $I_{DQ} = 0\text{ mA}$   | $V_{GS}$      | 0.9 | 1.4  | 1.9 | V             |

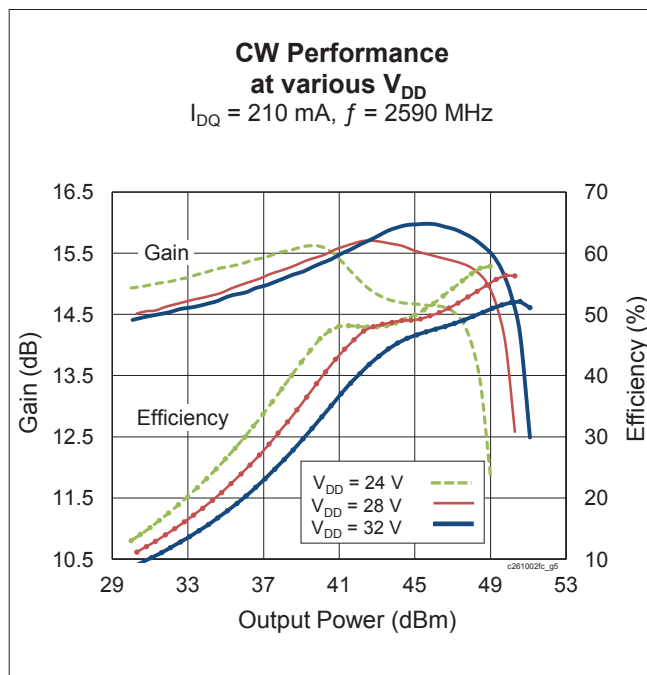
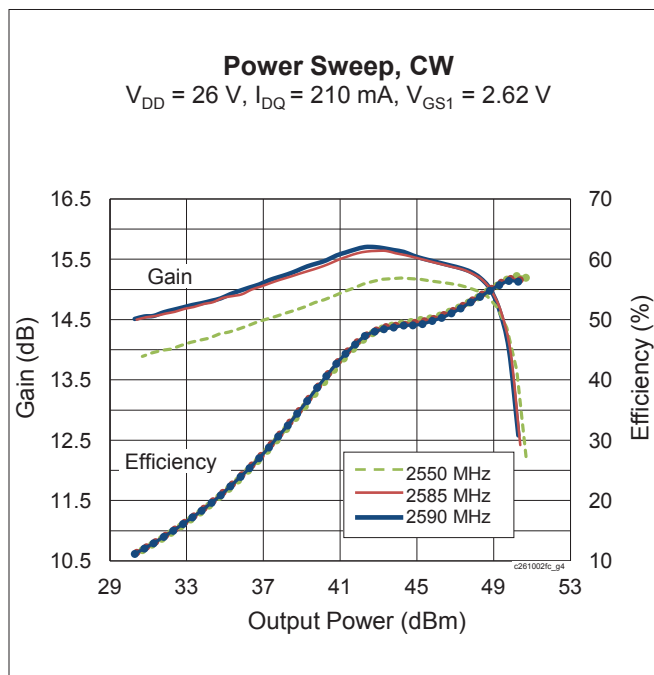
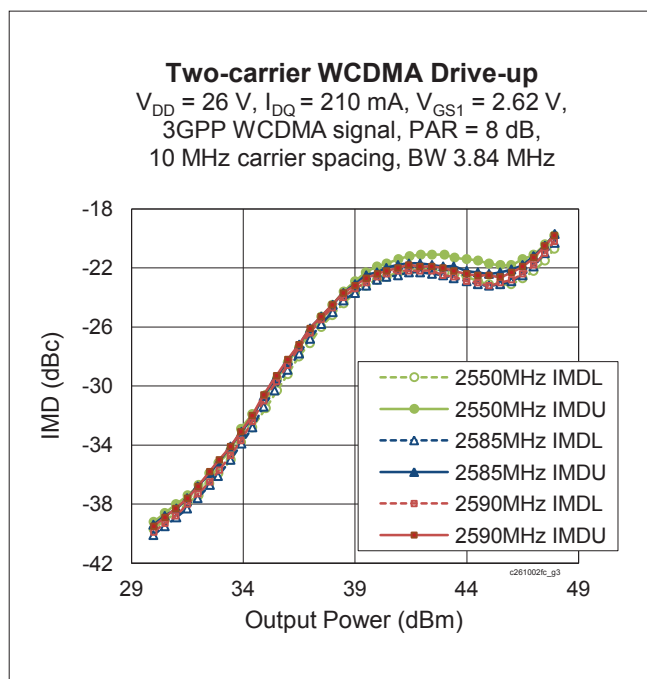
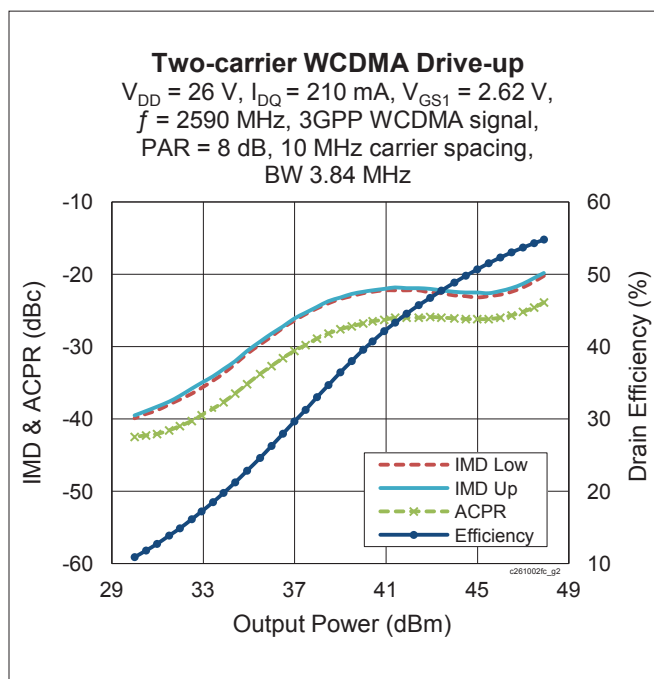
**Maximum Ratings**

| Parameter                                                                | Symbol          | Value       | Unit                 |
|--------------------------------------------------------------------------|-----------------|-------------|----------------------|
| Drain-Source Voltage                                                     | $V_{DSS}$       | 65          | V                    |
| Gate-Source Voltage                                                      | $V_{GS}$        | −6 to +10   | V                    |
| Operating Voltage                                                        | $V_{DD}$        | 0 to +32    | V                    |
| Junction Temperature                                                     | $T_J$           | 225         | $^{\circ}\text{C}$   |
| Storage Temperature Range                                                | $T_{STG}$       | −65 to +150 | $^{\circ}\text{C}$   |
| Thermal Resistance (Doherty, $T_{CASE} = 70^{\circ}\text{C}$ , 100 W CW) | $R_{\theta JC}$ | 0.6         | $^{\circ}\text{C/W}$ |

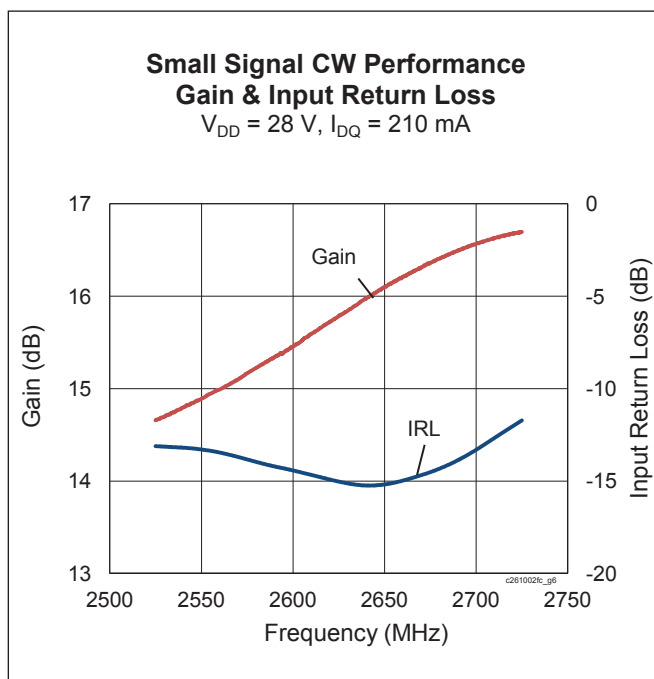
**Ordering Information**

| Type and Version     | Order Code           | Package and Description                             | Shipping             |
|----------------------|----------------------|-----------------------------------------------------|----------------------|
| PXAC261002FC V1 R0   | PXAC261002FC-V1-R0   | H-37248-4, open-cavity, push-pull, earless flange   | Tape & Reel, 50 pcs  |
| PXAC261002FC V1 R250 | PXAC261002FC-V1-R250 | H-37248-4, earless flange push-pull, earless flange | Tape & Reel, 250 pcs |

# Typical Performance (data taken in a production Doherty test fixture)



## Typical Performance (cont.)



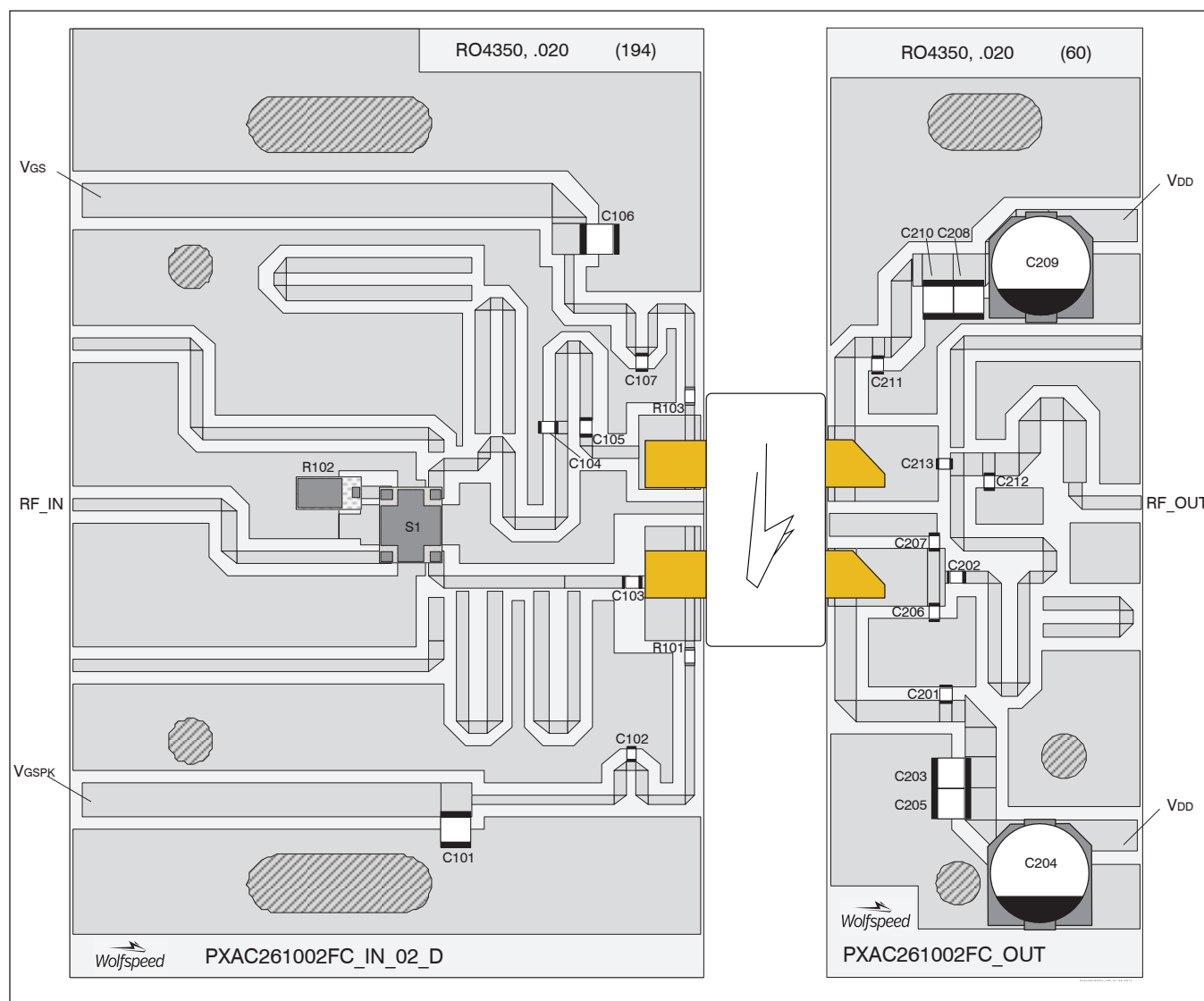
## Load Pull Performance

**Main Side Load Pull Performance** – Pulsed CW signal: 160  $\mu\text{s}$ , 10% duty cycle,  $V_{DD} = 28\text{ V}$ ,  $I_{DQ} = 240\text{ mA}$

| Freq<br>[MHz] | $Z_s$<br>[ $\Omega$ ] | P <sub>1dB</sub>      |              |                           |                         |            |                       |              |                           |                         |            |
|---------------|-----------------------|-----------------------|--------------|---------------------------|-------------------------|------------|-----------------------|--------------|---------------------------|-------------------------|------------|
|               |                       | Max Output Power      |              |                           |                         |            | Max PAE               |              |                           |                         |            |
|               |                       | $Z_L$<br>[ $\Omega$ ] | Gain<br>[dB] | P <sub>OUT</sub><br>[dBm] | P <sub>OUT</sub><br>[W] | PAE<br>[%] | $Z_L$<br>[ $\Omega$ ] | Gain<br>[dB] | P <sub>OUT</sub><br>[dBm] | P <sub>OUT</sub><br>[W] | PAE<br>[%] |
| 2540          | 13.3 – j23.8          | 5.7 – j10.9           | 16.8         | 46.58                     | 45                      | 50.3       | 10.9 – j7.1           | 19.1         | 45.1                      | 32                      | 59.5       |
| 2590          | 16.5 – j22.0          | 5.9 – j11.5           | 16.7         | 46.44                     | 44                      | 50.3       | 9.7 – j7.6            | 18.7         | 45.3                      | 34                      | 58.5       |
| 2640          | 21 – j24.7            | 6.4 – j11.5           | 16.8         | 46.35                     | 43                      | 50.0       | 10 – j6.2             | 19.1         | 44.9                      | 31                      | 58.0       |

**Peak Side Load Pull Performance** – Pulsed CW signal: 160  $\mu\text{s}$ , 10% duty cycle, 28 V,  $V_{GS1} = 1.4\text{ V}$

| Freq<br>[MHz] | $Z_s$<br>[ $\Omega$ ] | P <sub>1dB</sub>      |              |                           |                         |            |                       |              |                           |                         |            |
|---------------|-----------------------|-----------------------|--------------|---------------------------|-------------------------|------------|-----------------------|--------------|---------------------------|-------------------------|------------|
|               |                       | Max Output Power      |              |                           |                         |            | Max PAE               |              |                           |                         |            |
|               |                       | $Z_L$<br>[ $\Omega$ ] | Gain<br>[dB] | P <sub>OUT</sub><br>[dBm] | P <sub>OUT</sub><br>[W] | PAE<br>[%] | $Z_L$<br>[ $\Omega$ ] | Gain<br>[dB] | P <sub>OUT</sub><br>[dBm] | P <sub>OUT</sub><br>[W] | PAE<br>[%] |
| 2540          | 3.8-j12.1             | 11.8-j7.3             | 13.0         | 50                        | 100                     | 53.5       | 5.2-j5.3              | 14.4         | 48.4                      | 69                      | 63.4       |
| 2590          | 5.2-j12.8             | 13-j5.4               | 12.8         | 50                        | 100                     | 53.4       | 5.7-j5.6              | 14.2         | 48.5                      | 71                      | 62.2       |
| 2640          | 5.8-j13.3             | 14-j3.9               | 12.8         | 49.9                      | 98                      | 52.9       | 6.6-j6                | 14.2         | 48.4                      | 69                      | 61.0       |

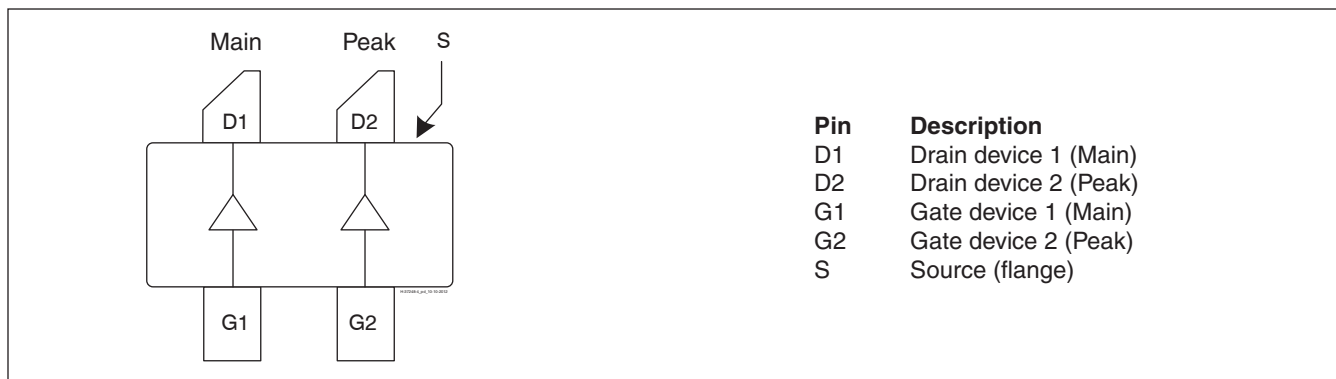
**Reference Circuit, 2545 – 2595 MHz***Reference circuit assembly diagram (not to scale)*

**Reference Circuit** (cont.)**Reference Circuit Assembly**

|                                                                                                                                            |                                                                                                 |
|--------------------------------------------------------------------------------------------------------------------------------------------|-------------------------------------------------------------------------------------------------|
| DUT                                                                                                                                        | PXAC261002FC V1                                                                                 |
| Test Fixture Part No.                                                                                                                      | LTA/PXAC261002FC V1                                                                             |
| PCB                                                                                                                                        | Rogers 4350, 0.508 mm [0.020"] thick, 2 oz. copper, $\epsilon_r = 3.66$ , $f = 2545 - 2595$ MHz |
| Find Gerber files for this test fixture on the Wolfspeed Web site at <a href="http://www.wolfspeed.com/RF">http://www.wolfspeed.com/RF</a> |                                                                                                 |

**Components Information**

| Component              | Description            | Suggested Manufacturer          | P/N              |
|------------------------|------------------------|---------------------------------|------------------|
| <b>Input</b>           |                        |                                 |                  |
| C101, C106             | Capacitor, 10 $\mu$ F  | Taiyo Yuden                     | UMK325C7106MM-T  |
| C102                   | Capacitor, 18 pF       | ATC                             | ATC800A180JT250T |
| C103                   | Capacitor, 1.6 pF      | ATC                             | ATC800A1R6CT250T |
| C104                   | Capacitor, 0.6 pF      | ATC                             | ATC800A0R6CT250T |
| C105, C107             | Capacitor, 12 pF       | ATC                             | ATC800A120JT250T |
| R101, R103             | Resistor, 10 ohm       | Panasonic Electronic Components | ERJ-3GEYJ100V    |
| R102                   | Resistor, 50 ohm       | Anaren                          | C16A50Z4         |
| S1                     | Hybrid coupler         | Anaren                          | X3C26P1-03S      |
| <b>Output</b>          |                        |                                 |                  |
| C201, C202             | Capacitor, 12 pF       | ATC                             | ATC800A120KT250T |
| C203, C205, C208, C210 | Capacitor, 10 $\mu$ F  | Taiyo Yuden                     | UMK325C7106MM-T  |
| C204, C209             | Capacitor, 220 $\mu$ F | Panasonic Electronic Components | EEE-FP1V221A     |
| C206                   | Capacitor, 0.5 pF      | ATC                             | ATC800A0R5CT250T |
| C207                   | Capacitor, 0.6 pF      | ATC                             | ATC800A0R6CT250T |
| C211                   | Capacitor, 12 pF       | ATC                             | ATC800A120JT250T |
| C212                   | Capacitor, 0.4 pF      | ATC                             | ATC800A0R4CT250T |
| C213                   | Capacitor, 3.9 pF      | ATC                             | ATC800A3R9CT250T |

**Pinout Diagram** (top view)

Lead connections for PXAC261002FC

## Package Outline Specifications

### Package H-37248-4

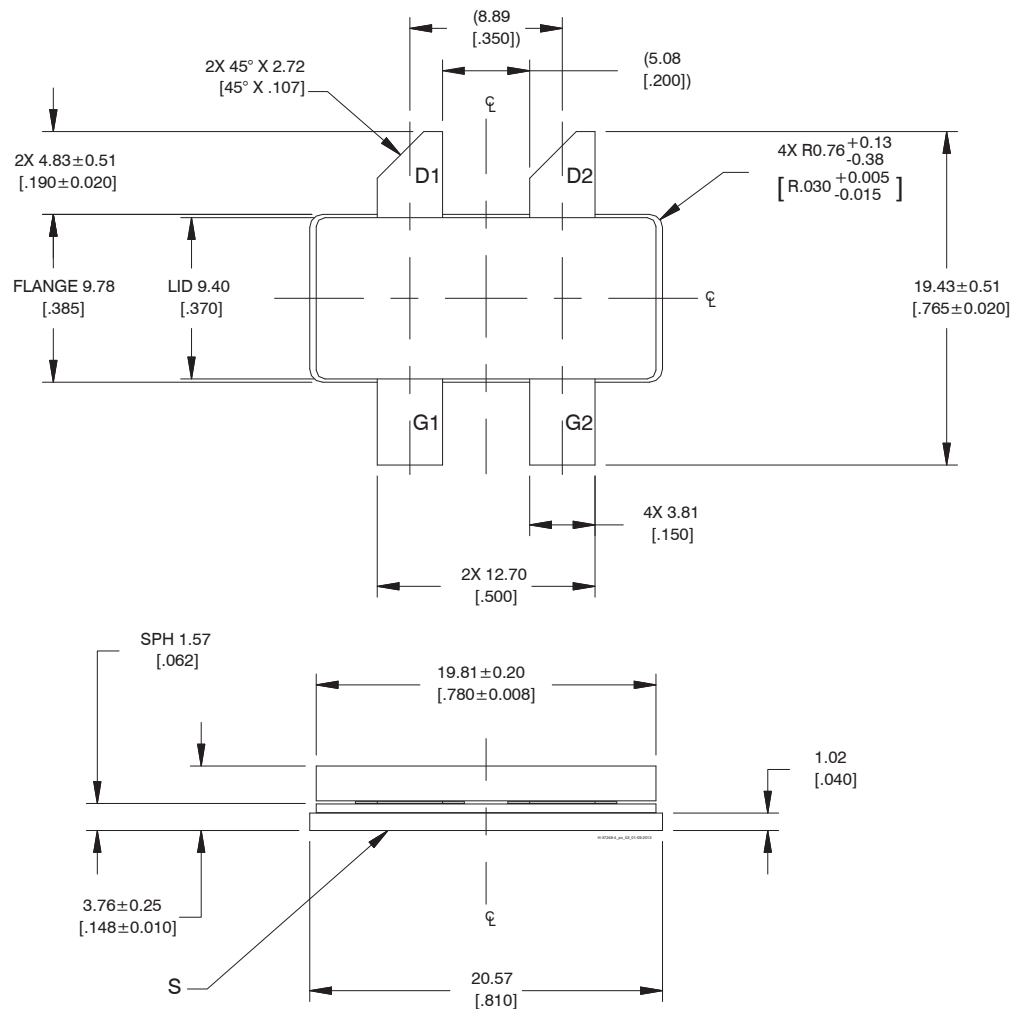


Diagram Notes—unless otherwise specified:

1. Interpret dimensions and tolerances per ASME Y14.5M-1994.
2. Primary dimensions are mm. Alternate dimensions are inches.
3. All tolerances  $\pm 0.127$  [.005] unless specified otherwise.
4. Pins: D1, D2 – drains; G1, G2 – gates; S – source.
5. Lead thickness:  $0.10 + 0.076/-0.025$  mm [ $0.004+0.003/-0.001$  inch].
6. Gold plating thickness:  $1.14 \pm 0.38$  micron [ $45 \pm 15$  microinch].

## Revision History

| Revision | Date       | Data Sheet Type | Page | Subjects (major changes since last revision)                                                                                                             |
|----------|------------|-----------------|------|----------------------------------------------------------------------------------------------------------------------------------------------------------|
| 01       | 2013-11-01 | Advance         | All  | Data Sheet reflects advance specification for product development                                                                                        |
| 02       | 2014-01-28 | Production      | All  | Data Sheet reflects released product specification<br>Revised all data and includes final specs, typical performance graphs, loadpull, reference circuit |
| 03       | 2014-03-26 | Production      | 1    | Corrected frequency range. Removed "doherty" from second feature. Updated feature 2.                                                                     |
| 03.1     | 2014-04-04 | Production      | 1    | Removed bullet point 4 (extra lines) from Features section.                                                                                              |
| 03.2     | 2016-06-07 | Production      | 1    | Added OPAR to RF table.                                                                                                                                  |
| 03.3     | 2016-06-15 | Production      | 1    | Adjust OPAR information.                                                                                                                                 |
| 04       | 2018-07-03 | Production      | All  | Converted to Wolfspeed Data Sheet.                                                                                                                       |

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## Notes

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